NSN 5961-01-200-4083

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-200-4083 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.080 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 28.0 reverse voltage, total rms and 48.0 nonrepetitive peak reverse voltage, peak total value and 40.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 60.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No